PNP Silicon Epitaxial Planar Transistor



CPH3106

DC/DC Converter Applications

Applications

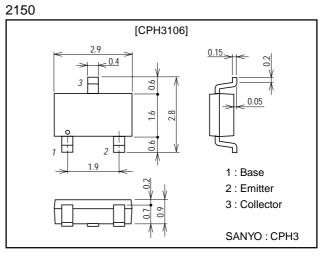
· Relay drivers, lamp drivers, motor drivers, strobes.

Features

- · Adoption of MBIT processes.
- · High current capacitance.
- · Low collector-to-emitter saturation voltage.
- · High speed switching.
- Ultrasmall-sized package permitting applied sets to be made small and slim (0.9mm).
- · High allowable power dissipation.

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at $Ta = 25^{\circ}C$

-				
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		-15	V
Collector-to-Emitter Voltage	VCEO		-12	V
Emitter-to-Base Voltage	VEBO		-5	V
Collector Current	IC		-3	A
Collector Current (Pulse)	ICP		-5	A
Base Current	IB		600	mA
Collector Dissipation	PC	Mounted on a ceramic board (600mm ² ×0.8mm)	0.9	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at $Ta = 25^{\circ}C$

Symbol	Conditions		Ratings		
Symbol		min	typ	max	Unit
ICBO	V _{CB} =-12V, I _E =0			-0.1	μA
IEBO	V _{EB} =-4V, I _C =0			-0.1	μA
hFE	$V_{CE} = -2V, I_{C} = -500 \text{mA}$	200		560	
fT	V _{CE} =-2V, I _C =-500mA		280		MHz
Cob	V _{CB} =-10V, f=1MHz		36		pF
V _{CE(sat)}	I _C =-1.5A, I _B =-30mA		-110	-165	mV
V _{BE(sat)}	I _C =-1.5A, I _B =-30mA		-0.85	-1.2	V
	IEBO hFE fT Cob VCE(sat)	ICBO VCB=-12V, IE=0 IEBO VEB=-4V, IC=0 hFE VCE=-2V, IC=-500mA fT VCE=-2V, IC=-500mA Cob VCB=-10V, f=1MHz VCE(sat) IC=-1.5A, IB=-30mA	ICBO VCB=-12V, IE=0 IEBO VEB=-4V, IC=0 hFE VCE=-2V, IC=-500mA fT VCE=-2V, IC=-500mA Cob VCB=-10V, f=1MHz VCE(sat) IC=-1.5A, IB=-30mA	Symbol Conditions min typ ICBO VCB=-12V, IE=0 IEBO VEB=-4V, IC=0 hFE VCE=-2V, IC=-500mA 200 fT VCE=-2V, IC=-500mA 280 Cob VCB=-10V, f=1MHz 36 VCE(sat) IC=-1.5A, IB=-30mA -110	Symbol Conditions min typ max ICBO VCB=-12V, IE=0 -0.1 -0.1 IEBO VEB=-4V, IC=0 -0.1 -0.1 hFE VCE=-2V, IC=-500mA 200 560 fT VCE=-2V, IC=-500mA 280 -0.1 Cob VCB=-10V, f=1MHz 36 -110 VCE(sat) IC=-1.5A, IB=-30mA -110 -165

Marking : AF

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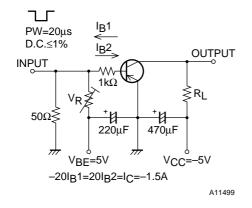
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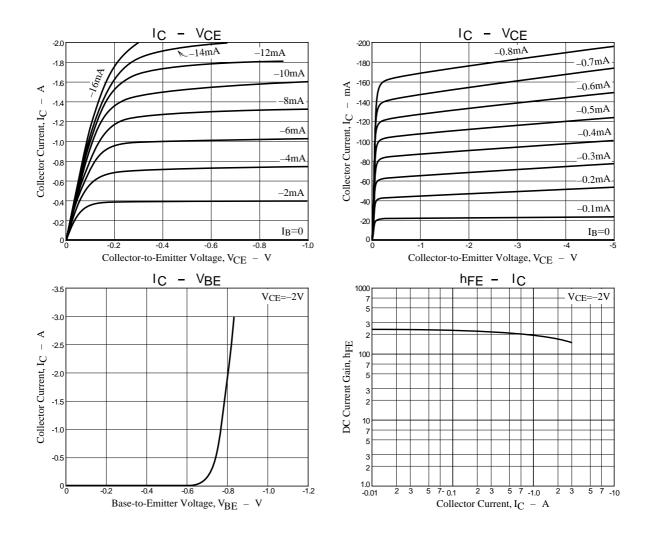
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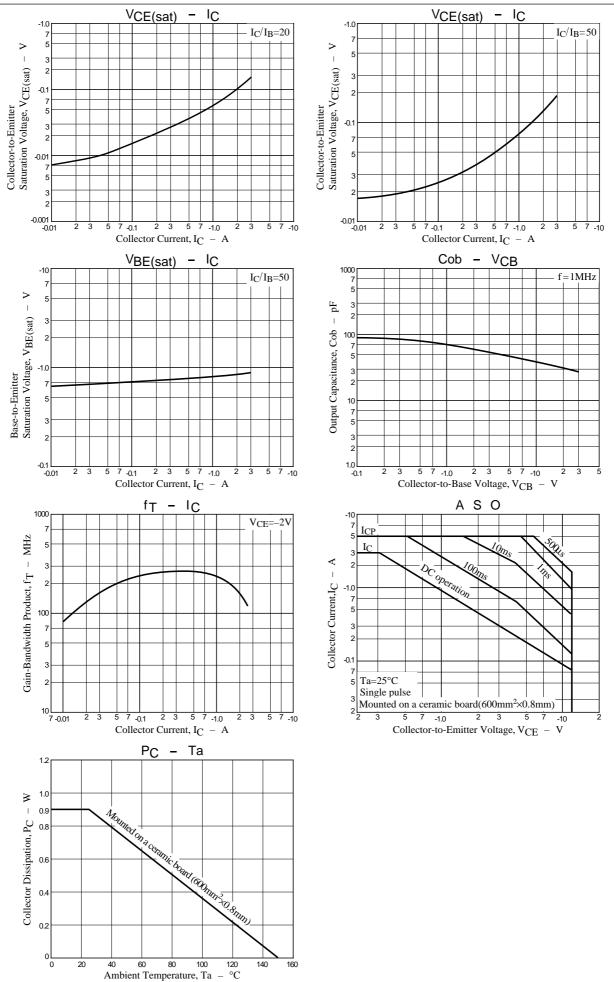
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Parameter	Symbol	Conditions	Ratings			Linit
			min	typ	max	Unit
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =-10μA, I _E =0	-15			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =−1mA, R _{BE} =∞	-12			V
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _C =-10µA, I _C =0	-5			V
Turn-ON Time	ton	See specified Test Circuit.		30		ns
Storage Time	tstg	See specified Test Circuit.		90		ns
Turn-OFF Time	t _f	See specified Test Circuit.		10		ns

Switching Time Test Circuit







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